

**Electronic supplementary information**

**Interfacial regulation of photoanodes for photoelectrochemical water splitting:  
the role of interlayer and overlayer**

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Configuration	Onset potential vs. RHE	Photocurrent density at 1.23 V <sub>RHE</sub>	ABPE	Stability	Published year <sup>[Ref.]</sup>
np <sup>+</sup> -Si/SiO <sub>x</sub> /NiFe	0.89 V	30.7 mA·cm <sup>-2</sup>	3.3%	100 h	2017 <sup>1</sup>
n-Si/SiO <sub>x</sub> /Al <sub>2</sub> O <sub>3</sub> /Pt/Ni/Ni(OH) <sub>2</sub>	0.997 V	19.2 mA·cm <sup>-2</sup>	~2%	200 h	2017 <sup>2</sup>
n-Si/SiO <sub>x</sub> /Ni@Ni(OH) <sub>2</sub>	1.03 V	36.4 mA·cm <sup>-2</sup>	~0.6%	300 h	2017 <sup>3</sup>
n <sup>+</sup> p-Si/SiO <sub>x</sub> /Ni/NiO <sub>x</sub> /NiFe-LDH	0.78 V	37 mA·cm <sup>-2</sup>	4.3%	68 h	2018 <sup>4</sup>
n-Si/ZrO <sub>2</sub> /NiFe	0.96 V	26.6 mA·cm <sup>-2</sup>	~1.3%	100 h	2018 <sup>5</sup>
n-Si/TiO <sub>2</sub> /NiAu	1.03 V	18.8 mA·cm <sup>-2</sup>	~1.2%	20 h	2018 <sup>6</sup>
n-Si/SiO <sub>x</sub> /SnO <sub>x</sub> /Ni	~0.9 V	~31.5 mA·cm <sup>-2</sup>	4.1%	100 h	2018 <sup>7</sup>
n-Si/SiO <sub>x</sub> /Al <sub>2</sub> O <sub>3</sub> /Ni/NiO <sub>x</sub> /NiOOH	0.85 V	28 mA·cm <sup>-2</sup>	3.0%	80 h	2019 <sup>8</sup>
n <sup>+</sup> p-Si/Ni/NiO	0.93 V	39.7 mA·cm <sup>-2</sup>	3.2%	100 h	2019 <sup>9</sup>
n-Si/NiSi <sub>x</sub> /NiO <sub>x</sub> /Au	0.88 V	34 mA·cm <sup>-2</sup>	~2.5%	10 h	2019 <sup>10</sup>
n <sup>+</sup> pp <sup>+</sup> -Si/Ni/NiO <sub>x</sub> /NiFe-C	0.84 V	38 mA·cm <sup>-2</sup>	5.1%	135 h	2019 <sup>11</sup>
n-Si/a-Si/TiO <sub>2</sub> /Ni	0.85 V	~33 mA·cm <sup>-2</sup>	3.91%	32 h	2020 <sup>12</sup>
n-Si/Ni/NiOOH/NiFe	1.0 V	25.2 mA·cm <sup>-2</sup>	1.42%	20 h	2020 <sup>13</sup>
n-Si/SiO <sub>x</sub> /NiFe	0.96 V	29.5 mA·cm <sup>-2</sup>	3.12%	14 h	2020 <sup>14</sup>
n-Si/Al <sub>2</sub> O <sub>3</sub> /Ni/NiFeO <sub>x</sub>	0.92 V	31 mA·cm <sup>-2</sup>	1.73%	330 h	2020 <sup>15</sup>
n-Si B implanted/NiSi/NiOOH	1.03 V	~17 mA·cm <sup>-2</sup>	~0.5%	20 h	2020 <sup>16</sup>
np <sup>+</sup> -Si/SiO <sub>2</sub> /Ni	0.7 V	~18 mA·cm <sup>-2</sup>	~1.2%	7 days	2021 <sup>17</sup>
n <sup>+</sup> p/SiO <sub>x</sub> /Fe/FeO <sub>x</sub> /NiOOH	1.01 V	24.1 mA·cm <sup>-2</sup>	3.0%	75 h	2021 <sup>18</sup>
n-Si NW/TiO <sub>2</sub> /In <sub>2</sub> O <sub>3</sub>	0.6 V	27 mA·cm <sup>-2</sup>	2.25%	5 h	2021 <sup>19</sup>
n-Si/SiO <sub>x</sub> /NiFe/Ni(OH) <sub>2</sub>	0.83 V	33.3 mA·cm <sup>-2</sup>	2.5%	100 h	2022 <sup>20</sup>
n-Si/SiO <sub>x</sub> /Cu/CuSCN	1.27 V	-	-	1 h	2022 <sup>21</sup>
SHJ/ITO/Ni/NiFe	0.84 V	38 mA·cm <sup>-2</sup>	4.8%	15 h	2022 <sup>22</sup>
n-Si/SiO <sub>x</sub> /AlO <sub>x</sub> /Au/Ni/NiFeO <sub>x</sub>	0.9 V	33 mA·cm <sup>-2</sup>	3.71%	50 h	2022 <sup>23</sup>

n-Si/TiO <sub>x</sub> /Ni	1.08 V	~14 mA·cm <sup>-2</sup>	~0.4%	600 h	2023 <sup>24</sup>
n-Si/ZrO <sub>2</sub> /Ni/NiO/Ir SAs	0.97 V	27.7 mA·cm <sup>-2</sup>	~1.6%	130 h	2023 <sup>25</sup>
n-Si/CoO <sub>x</sub> /NiFe-LDH	0.95 V	12.2 mA·cm <sup>-2</sup>	0.57%	2 h	2023 <sup>26</sup>
n-Si/CoO <sub>x</sub> /NiO <sub>x</sub> /FeOOH	0.96 V	22.6 mA·cm <sup>-2</sup>	2.52%	50 h	2024 <sup>27</sup>
HJ-Si/TiO <sub>2</sub> /stainless steel	0.84 V	31.65 mA·cm <sup>-2</sup>	3.39%	167 h	2024 <sup>28</sup>
n-Si/CuO <sub>x</sub> /NiO/NiCoFe-Bi	0.88 V	29.2 mA·cm <sup>-2</sup>	4.56%	100 h	2024 <sup>29</sup>
FTO/TiO <sub>2</sub> /nip-Si/NiO	0.11 V	0.65 mA·cm <sup>-2</sup>	0.29%	10 h	2025 <sup>30</sup>

**Table S1.** Selected representative results of n-Si based photoanodes with different interlayer and overlayer.

NOTE: The data marked with '~~' was obtained by approximately calculating from the figure in article.

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